

1A, 1MHz, Synchronous Step-Up DC-DC Converter UM3430AS SOT23-6 UM3430ADA DFN6 2.0×2.0

General Description

The UM3430A is a synchronous rectified, fixed frequency, step-up DC/DC converter delivering high efficiency in low profile SOT23-6 and DFN6 2.0×2.0 packages. The device features true output load disconnection and adjustable output with a current limit of 1A. With an internal NMOS switch, PMOS synchronous rectifier and high switching frequency of 1MHz, the UM3430A is capable of supplying 5.0V output at 500mA from single Li-ion cell or 300mA from 2 cell AA input using low profile inductors and ceramic capacitors. Current mode PWM control with internal compensation as well as the synchronous rectifier and 1MHz high frequency lead to the fewest number of external parts needed thereby saving BOM cost and PCB area. At light load, UM3430A enters automatically into pulse skipping mode to keep high efficiency. An internal dumping circuit will be connected to $V_{\rm IN}$ when the switch is idle that eliminates switch ringing and reduces EMI interference. Minimum $V_{\rm IN}$ operation after start-up is only limited by the battery's ability to provide the necessary power as it enters a deeply discharge state.

The device also features low shutdown current less than 1µA. It also limits the inductor current below to 500mA during start-up, minimizing surge currents seen by the input supply.

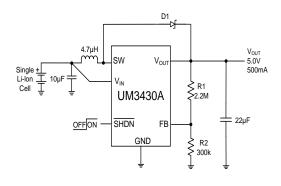
Applications

- Digital Cameras
- Handheld Instruments
- Wireless Handsets
- GPS Receivers
- Medical Instruments

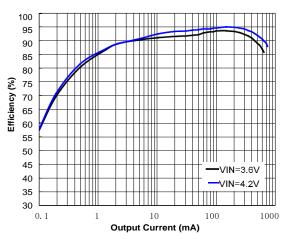
Features

- 5V at 500mA from single Li-Ion Cell
- Up to 94% Efficiency
- Output Load Disconnection
- Internal Synchronous Rectifier
- Input Current Limit 1A
- Pulse Skipping Mode Operation with Typical I_O as 48μA
- Shutdown Current Lower than 1 μA
- 1MHz Switching Frequency for Low Profile Inductor/Capacitor
- Minimum Start-Up Voltage: 2.3V
- Output Voltage: 2.5V to 5V
- Anti-Ringing Control to Reduce EMI

Typical Application Circuit



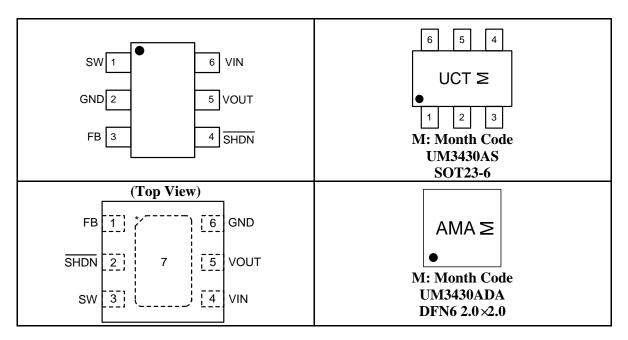
Efficiency vs. Output Current (Li-Ion to 5V)





Pin Configurations

Top View



Pin Description

Pin Number					
UM3430AS	UM3430AD A	Symbol	Description		
1	3	SW	Switch Pin. Connect external inductance to $V_{\rm IN}$. Keep these PCB trace lengths as short and wide as possible.		
2	6	GND	Ground. Provide a short direct PCB path between GND and the negative electrode of C_{OUT} and C_{IN} .		
3	1	FB	Feedback Input Pin. Connect to the center point of the external resistor divider and set the output voltage by: $V_{OUT} = 0.6V \left(1 + \frac{R1}{R2}\right)$		
4	2	SHDN	Logic Controlled Shutdown Input. Low logic active. In shutdown mode, all functions are disabled drawing <1 µA supply current. Do not leave SHDN floating.		
5	5	VOUT	Output Voltage Sense Input and Drain of the Internal Synchronous Rectifier P-MOSFET. Bias is derived from V _{OUT} . Keep PCB trace length from V _{OUT} to the output filter capacitor(s) as short and wide as possible.		
6	4	VIN	Battery Input Voltage. The device gets its start-up bias from $V_{\rm IN}$. Once $V_{\rm OUT}$ exceeds $V_{\rm IN}$, bias comes from $V_{\rm OUT}$. Thus, once started, operation is completely independent from $V_{\rm IN}$. Operation is only limited by the output power level and the battery's internal series resistance.		
-	7	Exposed Pad	The exposed pad must be soldered to the PCB ground plane. It serves as an additional ground connection and as a means of conducting heat away from the package.		



Ordering Information

Part Number	Packaging Type	Marking Code	Shipping Qty
UM3430AS	SOT23-6	UCT	3000pcs/7Inch
UM3430ADA	DFN6 2.0×2.0	AMA	Tape & Reel

Absolute Maximum Ratings (Note 1)

Symbol	Parameter	Value	Unit
$V_{ m IN}$	V _{IN} Supply Voltage	-0.3 to +6.0	V
V_{SW}	SW Voltage	-0.3 to +6.0	V
$ m V_{FB}$	FB Voltage	-0.3 to +6.0	V
$V_{\overline{SHDN}}$	SHDN Voltage	-0.3 to +6.0	V
V_{OUT}	Output Voltage	-0.3 to +6.0	V
T_{OP}	Operating Ambient Temperature Range	-40 to +85	$\mathcal C$
T_{STG}	Storage Temperature Range	-65 to +150	${\mathbb C}$
$T_{ m L}$	Maximum Lead Temperature (Soldering , 10s)	+260	\mathcal{C}

Note 1: Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



Electrical Characteristics

(V_{IN} =3.6V, V_{OUT} =5V, T_A =+25 °C, unless otherwise noted.)

Parameter	Test Conditions	Min	Тур	Max	Unit
Minimum Start-up Voltage	$I_{LOAD}=100mA, V_{OUT}=0V$		2.1	2.3	V
Minimum Operating Voltage	I _{LOAD} =100mA (Note 2)		1.2		V
Maximum Input Voltage		5.4			V
Adjustable Output Voltage Range		2.5		5.25	V
Feedback Voltage		0.588	0.6	0.612	V
Feedback Input Current	$V_{FB}=0.6V$		1	50	nA
Quiescent Current (Pulse Skipping Mode)	$V_{IN} = \frac{V_{FB} = 0.7V}{SHDN}$ (Note 3)		48		μА
Quiescent Current (Normal)	$V_{IN} = \frac{V_{FB} = 0.5V}{SHDN}$ (Note 3)		2.5		mA
Quiescent Current (Shutdown)	SHDN=0V			1	μА
NMOS Leakage Current	$V_{SW}=5V$		0.1	5	μΑ
PMOS Leakage Current	$V_{SW}=5V$, $V_{OUT}=0V$		0.1	5	μA
NMOS On-Resistance			0.25		Ω
PMOS On-Resistance			0.35		Ω
NMOS Current limit		900	1000	1200	mA
Pulse Skipping Mode Operation Current Threshold	L=4.7 μH		40		mA
Max Duty Cycle		80	90		%
Switching Frequency		0.8	1	1.2	MHz
SHDN Input High		2			V
SHDN Input Low				0.8	V
SHDN Input Current	SHDN=5.5V		0.01	1	μА
Soft-Start Time	\overline{SHDN} to 90% of V_{OUT}		1		ms

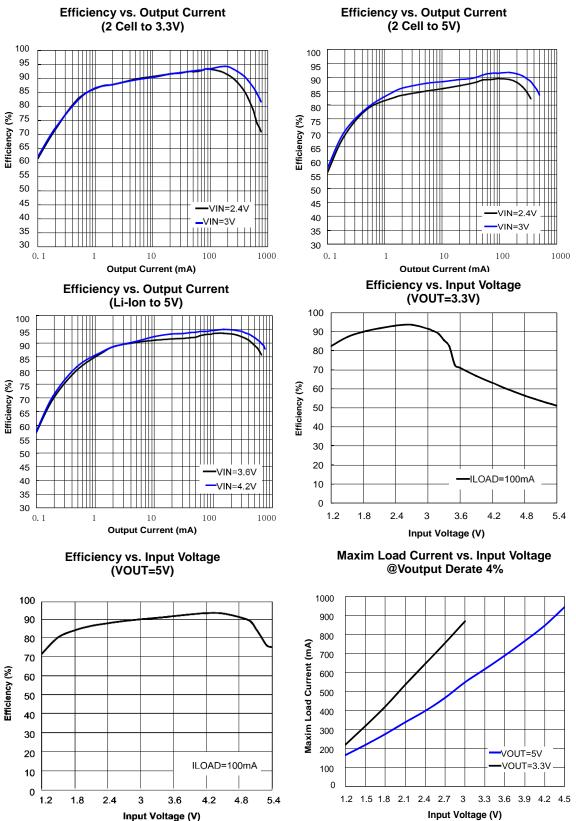
Note 2: Minimum V_{IN} operation after start-up is only limited by the battery's ability to provide the necessary power as it enters a deeply discharged state.

Note 3: Pulse skipping mode and normal operation I_Q is measured at V_{OUT} . The chip is in the open loop status and the inductor should not be soldered.



Typical Operating Characteristics

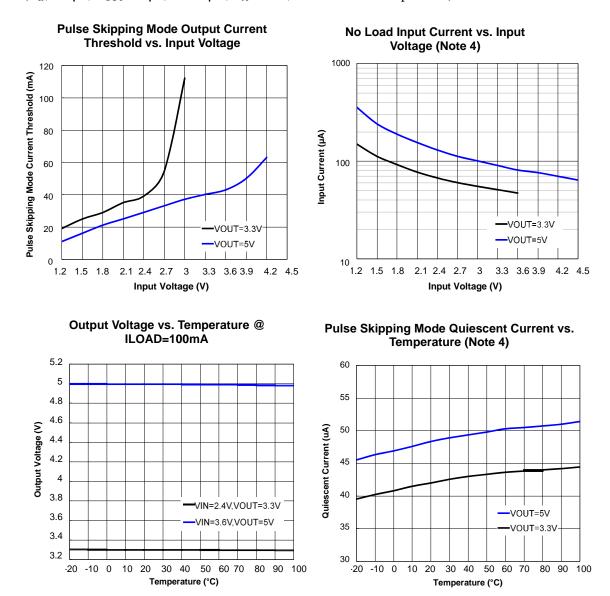
(C_{IN} =10 μF , C_{OUT} =22 μF , L=4.7 μH , T_A =25 $^{\circ}$ C, unless otherwise specified)





Typical Operating Characteristics (Continued)

 $(C_{IN}=10 \,\mu\text{F}, C_{OUT}=22 \,\mu\text{F}, L=4.7 \,\mu\text{H}, T_A=25 \,\text{C}, \text{unless otherwise specified})$



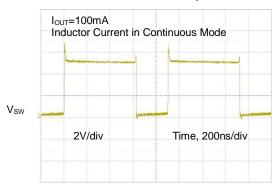
Note 4: No load input Current is measured at V_{IN} and Pulse Skipping Mode Quiescent Current is measured at V_{OUT} .



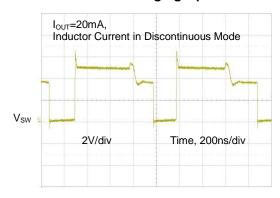
Typical Operating Characteristics (Continued)

 $(V_{IN}=3.6V, V_{OUT}=5V, C_{IN}=10 \mu F, C_{OUT}=22 \mu F, L=4.7 \mu H, TA=25 \,$ °C, unless otherwise specified)

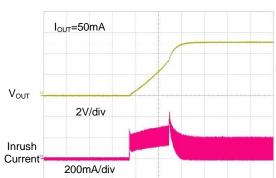
SW Pin Normal Mode Operation



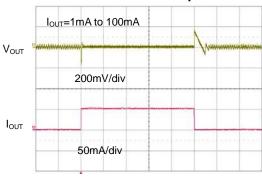
SW Pin Anti-Ringing Operation



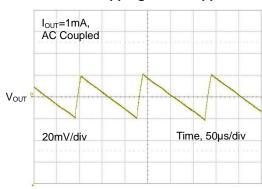
Inrush Current Control and Soft Start



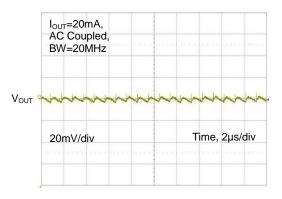
Load Transient Response



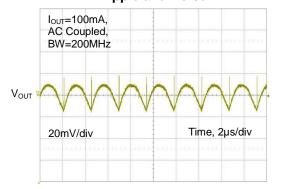
Pulse Skipping Mode Ripple



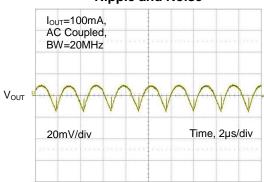
Ripple and Noise



Ripple and Noise

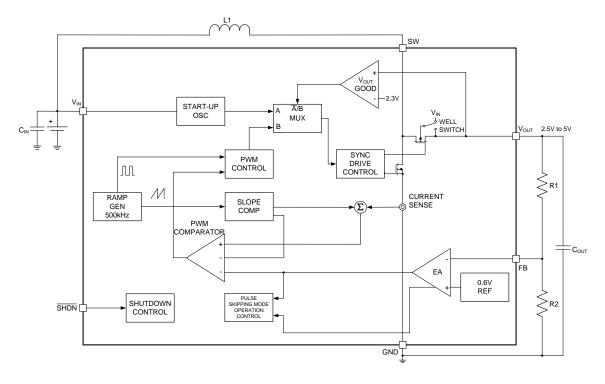


Ripple and Noise





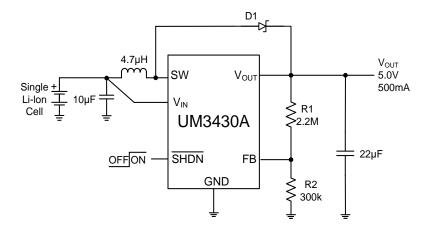
Block Diagram



Typical Application

Applications Where VOUT > 4.3V

When the output voltage is programmed above 4.3V, it is necessary to add a Schottky diode either from SW to VOUT in order to maintain an acceptable peak voltage on the SW pin. The Schottky diode between SW and VOUT will provide a peak efficiency improvement.



Function Description

The UM3430A is synchronous rectified, 1MHz fixed frequency, step-up DC/DC converter in low profile SOT23-6 and DFN6 2.0×2.0 packages. The device features low $R_{DS(ON)}$ internal MOSFET switches, current mode PWM controller and 0.6V internal reference voltage. Refer to the Block Diagram for better understanding.



Start-up

The device gets its start-up bias from $V_{\rm IN}$. Once $V_{\rm OUT}$ exceeds $V_{\rm IN}$, bias comes from $V_{\rm OUT}$. The soft-start time is typically 1ms. To minimize the inrush current, the chip is in the open loop operation in this status and the peak switch current is limited below to 500mA independent of input or output voltage.

NMOS Current Limit

The internal NMOS turns off while the inductor current reaches the current limit (I_{LIM}) typically 1000mA. There is approximately a 100ns delay from the time the current limit is reached and when the internal logic actually turns off the switch. During this 100ns delay, the peak inductor current will increase. It can be approximated by the following equation:

$$I_{\text{peak(typ)}} = I_{\text{LIM}} + \frac{V_{\text{IN}}}{L} \times 100 \text{ns}$$

This leads to the demand of a larger saturation current rating for the inductor.

Anti-Ringing Control

An internal dumping circuit will be connected from SW to V_{IN} to damp resonant circuit formed by L and C_{SW} when the inductor current is in the discontinuous mode. That eliminates switch ringing and reduces EMI interference.

Pulse Skipping Mode Operation

At very light loads, the UM3430A automatically enters Pulse Skipping Mode. In the Pulse Skipping Mode, the inductor current may reach zero or reverse on each pulse. The PWM control loop will automatically skip pulses to maintain output regulation. That improves the efficiency of the converter and saves energy of the battery.

Output Disconnection

The UM3430A is designed to allow true output disconnection by eliminating body diode conduction of the internal PMOS rectifier. This allows V_{OUT} to go to 0V during shutdown, drawing zero current form the input source. This function is realized by the well switch that connects the substrate to V_{IN} . Please refer to the Block Diagram for better understanding.

VIN>VOUT Operation

The UM3430A will maintain voltage regulation even if the input voltage is above the output voltage. Since the PMOS no longer acts as a low impedance switch in this mode, there will be more power dissipation within the IC. This will cause a sharp drop in the efficiency (see Typical Operating Characteristics, Efficiency vs. Input Voltage). The maximum output current should be limited in order to maintain an acceptable junction temperature, 100mA is usually acceptable.

Applications Information

Output Voltage Setting

The external resistor divider sets the output voltage. Choose R2 around $300k\Omega$ for optimal transient response and feedback leakage current. V_{OUT} is set by:



$$V_{OUT} = 0.6V \left(1 + \frac{R1}{R2}\right)$$

Inductor Selection

A $2.2\,\mu H$ to $4.7\,\mu H$ inductor with DC current rating at least 1.5A is recommended for most applications of UM3430A.

Larger values of inductance will allow greater output current capability by reducing the inductor ripple current. Increasing the inductance above $6.8\,\mu\text{H}$ will increase size while providing little improvement in output current capability.

For best efficiency, the inductor DC resistance shall be as small as possible to reduce the I²R power losses. As the switching frequency is up to 1MHz, inductor losses are closely related to the magnetic core materials. High frequency ferrite core inductors are preferred to comparatively cheap powered iron core ones. To minimize radiated noise, use a toroid, pot core or shielded bobbin inductor. See Table 1 for some suggested inductors and suppliers.

Table 1. Recommended Inductors

Part	L (µH)	Max DCR (mΩ)	Height (mm)	Supplier	
74404041047	4.7	91	1.2	W ürth Elektronik www.we-online.com	
CDRH5D16NP	4.7	64	1.8	Sumida www.sumida.com	
VLF5014S	4.7	98	1.4	TDK www.component.tdk.com	
MSS6122	4.7	65	2.2	Coilcraft www.coilcraft.com	

Input and Output Capacitor Selection

Low ESR capacitors should be used to minimize the output voltage ripple, input switching noise and the peak current drawn from the battery. Multilayer ceramic capacitors are an excellent choice as they have extremely low ESR and are available in small footprints. X5R and X7R dielectric materials are recommended.

A $10\,\mu\text{F}$ input capacitor and a $22\,\mu\text{F}$ output capacitor is sufficient for most applications of UM3430A. At the application that the maximum output current is less than 300mA, a $4.7\,\mu\text{F}$ input capacitor and a $10\,\mu\text{F}$ output capacitor is feasible. To minimize the output voltage ripple and improve the transient response, an larger input and output capacitor can be used. Table 2 below shows a list of several ceramic capacitor suppliers.

Table 2. Recommended Capacitor Suppliers Information

Supplier	Website		
AVX	www.avxcorp.com		
Murata	www.murata.com		
Fenghua	www.china-fenghua.com		
Samsung Electro-Mechanics	www.samsungsem.com		

Layout Guidance

When laying out the PC board, the following suggestions should be taken to ensure proper operation of the UM3430A.

1. Consideration should be taken first to place C_{OUT} as closely as possible to the V_{OUT} and GND



pins.

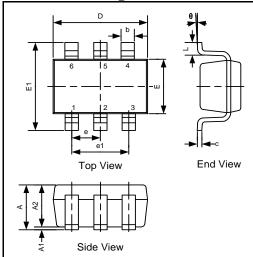
- 2. The power traces, including the GND, SW, V_{IN} and V_{OUT} should be kept short, direct and wide to allow large current flow.
- 3. Connect the input capacitor C_{IN} to the GND pin as closely as possible to get good power filter effect and reduce ground bounce.
- 4. Keep the switching node away from the sensitive FB node.
- 5. Do not trace signal line under inductor.
- 6. Keep the GND plane under the converter as complete as possible in double-sided PCB board.
- 7. For the UM3430ADA, connect pin 4, 8 and the expose pad together to the ground plane by vias to conduct the heat away from the package.



Package Information

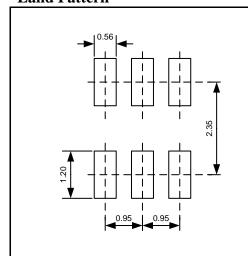
UM3430AS: SOT23-6

Outline Drawing



DIMENSIONS							
Symbol	MILI	LIMET	ERS	INCHES			
	Min	Тур	Max	Min	Тур	Max	
A	1.013	1.15	1.40	0.040	0.045	0.055	
A1	0.00	0.05	0.10	0.000	0.002	0.004	
A2	1.00	1.10	1.30	0.039	0.043	0.051	
b	0.30	-	0.50	0.012	-	0.020	
С	0.10	0.15	0.20	0.004	0.006	0.008	
D	2.82	-	3.10	0.111	-	0.122	
Е	1.50	1.60	1.70	0.059	0.063	0.067	
E1	2.60	2.80	3.00	0.102	0.110	0.118	
e	0.95REF 0.037REF				F		
e1	1.90REF			().075RE	F	
L	0.30	-	0.60	0.012	-	0.024	
θ	0 °	-	8°	0 °	-	8°	

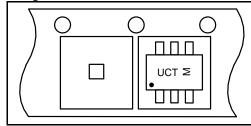
Land Pattern



NOTES:

- 1. Compound dimension: 2.92×1.60;
- 2. Unit: mm;
- 3. General tolerance ±0.05mm unless otherwise specified;
- 4. The layout is just for reference.

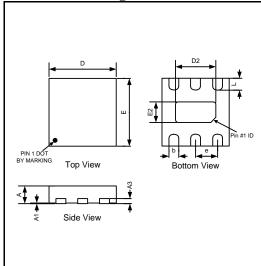
Tape and Reel Orientation





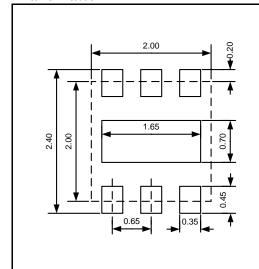
UM3430ADA: DFN6 2.0×2.0

Outline Drawing



DIMENSIONS							
Symbol	MIL	LIME	TERS	INCHES			
	Min	Тур	Max	Min	Тур	Max	
A	0.55	ı	0.80	0.022	1	0.031	
A1	0.00	-	0.05	0.000 - 0.002		0.002	
A3	0.20REF			0.008REF			
b	0.25	0.30	0.35	0.010 0.012 0.01		0.014	
D	1.924	2.00	2.076	0.076	0.079	0.082	
D2	1.35	-	1.75	0.053	-	0.069	
Е	1.924	2.00	2.076	0.076 0.079 0.082		0.082	
E2	0.65	-	1.06	0.026	-	0.042	
e	0.65BSC			C	.026BS0	C	
L	0.224	-	0.45	0.009 - 0.018			

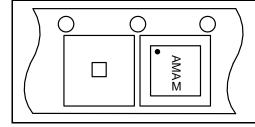
Land Pattern



NOTES:

- 1. Compound dimension: 2.00×2.00;
- 2. Unit: mm;
- 3. General tolerance ±0.05mm unless otherwise specified;
- 4. The layout is just for reference.

Tape and Reel Orientation





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